

The TDK4 is a medium voltage, high current, thin pack disc SCR employing a amplifying gate structure. This thin package provides greater cooling thus maximizing high current performance. The amplifying gate design allows the SCR to be reliably operated at high di/dt and dv/dt conditions in various phase control applications.

FEATURES:

- Low On-State Voltage
- High di/dt Capability
- High dv/dt Capability
- Hermetic Ceramic Package
- Excellent Surge and I²t Ratings

APPLICATIONS:

- DC Power Supplies
- Motor Controls
- Plating Rectifiers

ORDERING INFORMATION

Select the complete 12 digit Part Number using the table below.
 EXAMPLE: TDK4223802DH is a 2200V 3800A SCR with 300ma IGT and 12 inch gate and cathode potential leads.

PART	Voltage Rating $V_{DRM}-V_{RRM}$	Voltage Code	Current Rating I_{tavg}	Current Code	Turn-Off t_q	Gate I_{GT}	Leads
TDK4	2400	24	3800	38	0	2	
	2200	22					
	2000	20			500us	300ma	12"
	1800	18			(typ.)	(max)	

Absolute Maximum Ratings

Characteristic	Symbol	Rating	Units
Repetitive Peak Voltage	$V_{DRM}-V_{RRM}$	2400	Volts
Average On-State Current, $T_C=70^\circ\text{C}$	$I_{T(Avg.)}$	3800	A
RMS On-State Current, $T_C=70^\circ\text{C}$	$I_{T(RMS)}$	5969	A
Average On-State Current, $T_C=54^\circ\text{C}$	$I_{T(Avg.)}$	4500	A
RMS On-State Current, $T_C=54^\circ\text{C}$	$I_{T(RMS)}$	7069	A
Peak One Cycle Surge Current, 60Hz, $V_R=0V$	I_{TSM}	75,000	A
Peak One Cycle Surge Current, 50Hz, $V_R=0V$	I_{TSM}	70,000	A
Fuse Coordination I^2t , 60Hz	I^2t	2.34E+07	A^2s
Fuse Coordination I^2t , 50Hz	I^2t	2.45E+07	A^2s
Critical Rate-of-Rise of On-State Current	di/dt	100	A/us
Repetitive			
Critical Rate-of-Rise of On-State Current	di/dt	200	A/us
Non-Repetitive			
Peak Gate Power, 100us	P_{GM}	300	Watts
Average Gate Power	$P_{G(avg)}$	50	Watts
Operating Temperature	T_j	-40 to+125	$^\circ\text{C}$
Storage Temperature	$T_{Stg.}$	-50 to+150	$^\circ\text{C}$
Approximate Weight		6.5	lb
		2.95	Kg
Mounting Force		16,000-20,000	lbs
		71.2 - 89.0	KNewtons

Information presented is based upon limited testing or projected capabilities.
This information is subject to change without notice. The manufacturer makes
no claim as to suitability for use, reliability, capability or future availability of this
product.

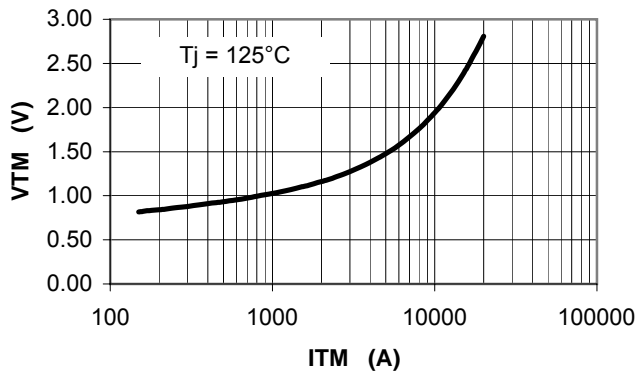
Electrical Characteristics, Tj=25°C unless otherwise specified

Characteristic	Symbol	Test Conditions	Rating			Units
			min	typ	max	
Repetitive Peak Forward Leakage Current	I_{DRM}	Tj=125°C, V_{DRM} =Rated			250	ma
Repetitive Peak Reverse Leakage Current	I_{RRM}	Tj=125°C, V_{RRM} =Rated			250	ma
Peak On-State Voltage	V_{TM}	Tj=125°C, I_{TM} =4000A			1.38	V
V_{TM} Model, Low Level	V_0	Tj=125°C			0.954	V
$V_{TM} = V_0 + r \cdot I_{TM}$	r	20% $I_{TM} - \pi \cdot I_{TM}$			9.94E-02	mΩ
V_{TM} Model, High Level	V_0	Tj=125°C			1.130	V
$V_{TM} = V_0 + r \cdot I_{TM}$	r	$\pi \cdot I_{TM} - I_{TSM}$			8.37E-02	mΩ
V_{TM} Model, 4-Term	A	Tj=125°C			0.453	
$V_{TM} = A + B \cdot \ln(I_{TM}) +$	B	20% $I_{TM} - I_{TSM}$			0.069	
$C \cdot (I_{TM}) + D \cdot (I_{TM})^{1/2}$	C				8.00E-05	
	D				5.14E-04	
Turn-On Delay Time	t_d	$V_D = 0.5 \cdot V_{DRM}$ Gate Drive: 40V - 20Ω		3		us
Turn-Off Time	tq	Tj=125°C $dv/dt = 20V/us$ to 67% V_{DRM}			500	us
$dv/dt_{(crit)}$	dv/dt	Tj=125°C Exp. Waveform $V_D = 67\%$ Rated	800			V/us
Gate Trigger Current	I_{GT}	Tj=25°C $V_D = 12V$	30	150	300	ma
Gate Trigger Voltage	V_{GT}		0.8	2.0	5.0	V
Peak Reverse Gate Voltage	V_{GRM}				5	V

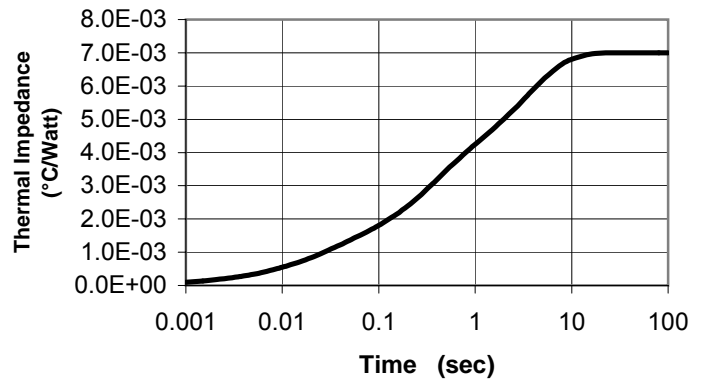
Thermal Characteristics

Characteristic	Symbol	Test Conditions	Rating			Units	
			min	typ	max		
Thermal Resistance							
Junction to Case	$R\theta_{jc}$	Double side cooled		0.006	0.007	°C/Watt	
Case to Sink	$R\theta_{cs}$	Double side cooled		0.001	0.0015	°C/Watt	
Thermal Impedance Model							
$Z\theta_{jc}(t) = \Sigma(A(N) \cdot (1 - \exp(-t/\text{Tau}(N))))$		Double side cooled					
	where:		N =	1	2	3	4
			A(N) =	1.43E-04	9.08E-04	2.37E-03	3.58E-03
			Tau(N) =	2.62E-03	2.31E-02	3.05E-01	3.40E+00

Maximum On-State Voltage Drop

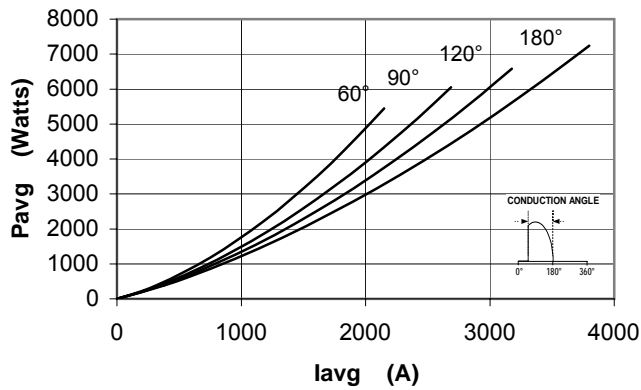


MAXIMUM TRANSIENT THERMAL IMPEDANCE



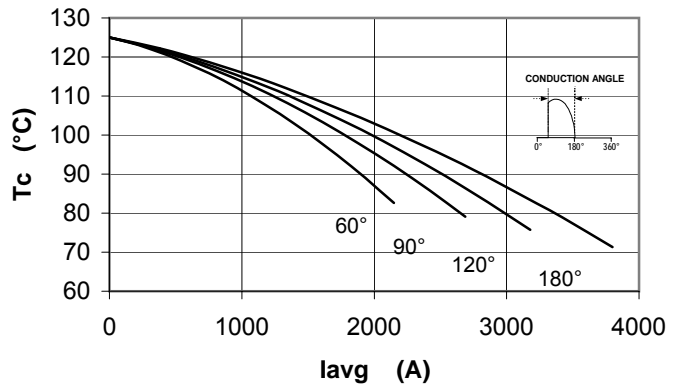
Maximum On-State Power Dissipation

Sinusoidal Waveform



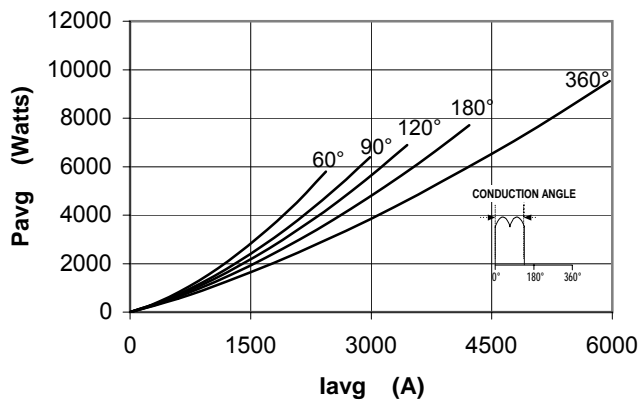
Maximum Allowable Case Temperature

Sinusoidal Waveform



Maximum On-State Power Dissipation

Square Waveform



Maximum Allowable Case Temperature

Square Waveform

